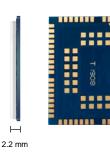


Quectel BG95-M9

LTE Cat M1/Cat NB2 Module For 450 MHz & 410 MHz Spectrum





The BG95-M9 LTE Cat M1/Cat NB2 module is specially designed for LTE networks deployed over the 450 MHz (B31/B72/B73) and 410 MHz (B87/B88) spectrum. The 450 MHz and 410 MHz bands support Power Class levels at Power Class 2 (26 dBm) while other LTE-FDD bands support Power Class 3 (23 dBm). The module is 3GPP Rel-14 compliant and offers maximum data rates of 588 kbps downlink and 1119 kbps uplink under LTE Cat M1. It features ultra-low power consumption by leveraging the integrated RAM/flash as well as the ARM Cortex A7 processor supporting ThreadX, achieving up to 70 % reduction in PSM leakage and 85 % reduction in eDRX current consumption compared to its predecessor.

BG95-M9 boasts a comprehensive set of hardware-based security features and enables trusted applications to run directly on the Cortex A7 TrustZone engine. Additionally, it provides pin-to-pin compatibility with Quectel LTE Cat 1/Cat 4 modules EG91/EG95, LTE Cat M1/Cat NB1/EGPRS module BG96, UMTS/HSPA modules UG95/UG96 and GSM/GPRS module M95.

With a cost-effective SMT form factor of 23.6 mm \times 19.9 mm \times 2.2 mm and high integration level, BG95-M9 enables integrators and developers to easily design their applications and take advantage from the module's low power consumption and mechanical intensity. Its advanced LGA package allows fully automated manufacturing for high-volume applications. A rich set of Internet protocols, industry-standard interfaces and abundant functions extend the applicability of the module to a wide range of M2M applications such as wireless POS, smart metering, tracking, wearable devices, etc.



Key Features

- ✓ LTE Cat M1/Cat NB2 module with ultra-low power consumption
- ✓ Easy migration from Quectel GSM/GPRS, UMTS/HSPA and LTE modules
- ✓ Support 450 MHz LTE-FDD bands B31, B72 and B73 at Power Class 2
- ✓ Support 410 MHz LTE-FDD bands B87 and B88 at Power Class 2
- ✓ Support Power Class 3 for other LTE-FDD bands
- ✓ Integrated RAM and flash in the baseband chipset
- ✓ Comprehensive set of hardware-based security features
- ✓ Fast time-to-market: reference designs, evaluation tools and timely technical support minimize design-in time and development efforts
- Compact SMT form factor ideal for size-constrained applications with tight space
- ✓ Robust mounting and interfaces



LTE Cat M1 & Cat NB2



Embedded Abundant Protocols



450 MHz and 410 MHz Bands Supported



DFOTA



LGA Package



USB 2.0 Interface



Ultra-low Power Consumption



Quectel Enhanced AT Commands



Integrated RAM/ Flash in Chipset

Version: 1.0.0 | Status: Preliminary

Quectel BG95-M9

		Queetel Bess Mis
LPWA Module		BG95-M9
Region/Operator		Global
Dimensions		23.6 mm × 19.9 mm × 2.2 mm
Temperature Ran	ge	
Operating Temperature		-35 °C to +75 °C
Extended Temperature		-40 °C to +85 °C
Frequency Bands		
LTE-FDD		Cat M1: B1/B2/B3/B4/B5/B8/B12/B13/B18/B19/B20/B25/B26/B27/B28/B31*①/B66/B72*①/B73*①/ B85/B86*/B87*①/B88*① Cat NB2: B1/B2/B3/B4/B5/B8/B12/B13/B18/B19/B20/B25/B28/B31*①/B66/B72*①/B73*①/ B85/B86*/B87*①/B88*①
GNSS		GPS/GLONASS/BeiDou/Galileo/QZSS
Certifications		
Regulatory		CE*, Anatel*
Carrier		TBD
Data Rate		
LTE-M		Cat M1: Max. 588 kbps (DL)/ Max. 1119 kbps (UL)
NB-IoT		Cat NB2: Max. 127 kbps (DL)/Max. 158.5 kbps (UL) Cat NB1: Max. 32 kbps (DL)/Max. 70 kbps (UL)
Interfaces		
(U)SIM		× 1 (1.8 V only)
UART		×3
USB 2.0		×1
PCM*		× 1 (For VoLTE Only)
I2C*		× 1 (For VoLTE Only)
GPIO		×9
Antenna		× 2 (For LTE & GNSS Antennas)
Voice*		
Voice *		VoLTE for Cat M1
SMS		
SMS		Point-to-point MO/MT; SMS Cell Broadcast; Text and PDU Mode
		Tollit to politi Mo/MT, 3M3 cell broadcast, Text and T bo Mode
Enhanced Features		Vis UCD into force
Firmware Upgrade		Via USB interface
DFOTA		Delta Firmware Upgrade Over-the-Air
Processor		ARM A7 Processor
QuecOpen®		Simplifies the Development of Embedded Applications
QuecLocator®		Supports Cell ID Positioning
SoftSIM		Supported
Software Features		
Protocols		PPP/TCP/UDP/SSL/TLS/FTP(S)/NITZ/PING/MQTT/LwM2M/CoAP/IPv6
Drivers		USB Serial Driver: Windows 7/8/8.1/10; Linux 2.6–5.14; Android 4.x–11.x GNSS/RIL Driver: Android 4.x–11.x
Electrical Features		
Supply Voltage Range		3.2–4.2 V, typ. 3.8 V
Max. Output Power		26 dBm @ B31/B72/B73/B87/B88 23 dBm @ other LTE Bands
Power Consumption @ PSM		TBD
Power Consumption @ LTE Cat M1	Sleep Mode	TBD
	Idle Mode	TBD
	Active Mode	TBD
Power	Sleep Mode	TBD
Consumption @ LTE Cat NB1	Idle Mode	TBD
	Active Mode	TBD

NOTE:



^{1. *:} under development/in-progress.

^{2.} ①: LTE-FDD B31, B72, B73, B87 and B88 support Power Class 2 (26 dBm).